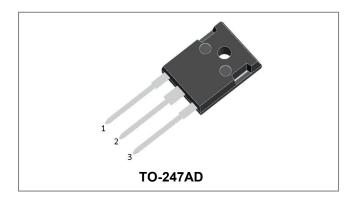






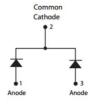
MBR20150WT SCHOTTKY RECTIFIER



Features

- 175°C T_J operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	150	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=133°C, rectangular wave form	10(Per Leg) 20(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	150	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V_{F1}	@ 10A, Pulse, T _J = 25 °C	0.74	0.88	V
(Per Leg)*	V _{F2}	@ 10A, Pulse, T _J = 125 °C	0.61	0.78	V
Reverse Current (Per Leg)*	I _{R1}	@V _R = rated VR Pulse T _J = 25 °C	0.004	1	mA
	I _{R2}	@V _R = rated VR , Pulse T _J = 125 °C	2.0	6.0	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	380	400	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse width < 300 µs, duty cycle < 2%

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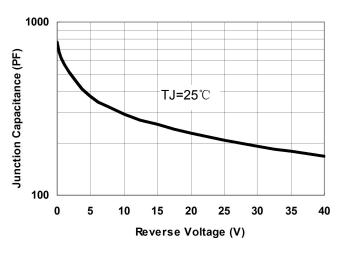




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-65 to +175	°C
Storage Temperature	T _{stg}	-	-65 to +175	°C
Typical Thermal Resistance Junction to	R _θ JC	DC operation	2.20(Per Leg)	°C/W
Case			1.10(Per Device)	C/VV
Typical Thermal	R₀cs	Mounting surface, smooth and	0.24	°C/W
Resistance, Case to Heat Sink		greased		
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AD			

Ratings and Characteristics Curves



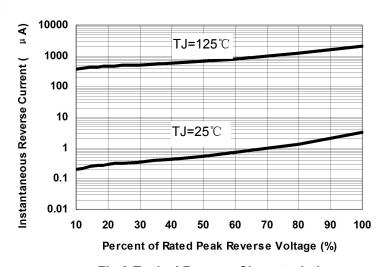


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

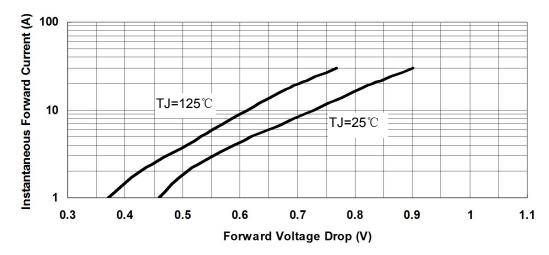


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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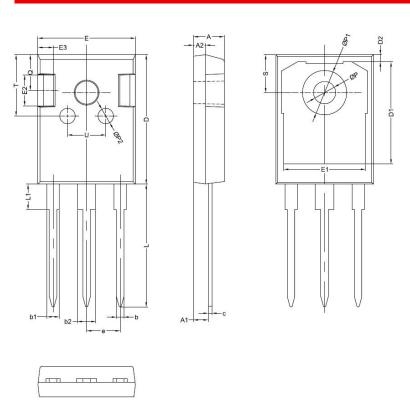








Mechanical Dimensions TO-247AD



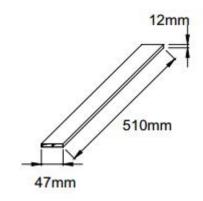
OVMDOL	Millimeters				
SYMBOL	MIN.	TYP.	MAX.		
Α	4.80	5.00	5.20		
A1	2.20	2.41	2.61		
A2	1.90	2.00	2.10		
b	1.10	1.20	1.40		
b1	1.80	2.00	2.20		
b2	2.80	3.00	3.20		
С	0.50	0.60	0.75		
D	20.30	21.00	21.20		
D1		16.55			
D2		1.20			
E	15.45	15.80	16.00		
E1		13.30			
E2		5.00			
E3		2.50			
е		5.44			
L	19.42	19.92	20.70		
L1		4.13			
Р	3.50	3.60	3.70		
P1	7.1		7.40		
P2		2.50			
Q		5.80			
Q S T	6.05	6.15	6.25		
T		10.00			
U		6.20			

Ordering Information:

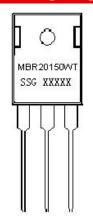
Device	Package	Shipping	
MBR20150WT	TO-247AD(Pb-Free)	25pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

= Device Type = Forward Current (20A) MBR 20 150 = Reverse Voltage (150V) WT = Configuration

SSG = SSG = Year WW = Week = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

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